

# Plastic Infrared Emitting Diode

## OP140, OP145 Series



### Features:

- IR-transmissive plastic package
- Side-looking package for space-limited applications
- Wide irradiance pattern
- Mechanically and spectrally matched to other OPTEK products

### Description:

Each device in this series is a high intensity gallium arsenide infrared emitting diode that is suited for use as a PCBoard mounted slotted switch or an easy mount PCBoard interrupter.

Each **OP140** (A, B, C, D) and **OP145** (A, C) device is a domed-lens 935 nm diode that is molded in an IR-transmissive plastic side-looking package.

*OP140 is mechanically and spectrally matched to the OP550 series of phototransistors and the OP560 series of photodarlington. OP145 is mechanically and spectrally matched to the OP555 and OP565 series devices.*

*Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.*

### Applications:

- Space-limited applications
- PCBoard mounted slotted switch
- PCBoard interrupter

Ordering Information				
Part Number	LED Peak Wavelength	Lens Type	Total Beam Angle	Lead Length
OP140A	935 nm	Domed	40°	min of 0.50"
OP140B				
OP140C				
OP140D				
OP145A				
OP145C				



RoHS

### General Note

TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

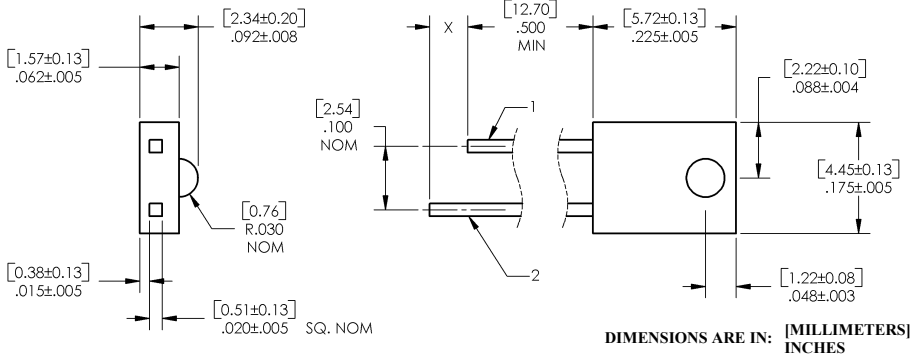
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OP140, OP145 Series

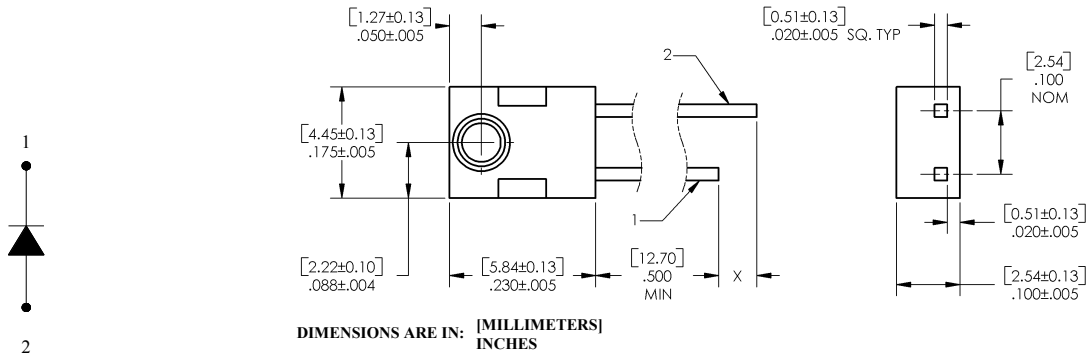


## OP140 (A, B, C, D)



Pin #	LED	Sensor
1	Cathode	Emitter/Anode
2	Anode	Collector/Cathode

## OP145 (A, C)



Pin #	LED	Sensor
1	Cathode	Emitter/Anode
2	Anode	Collector/Cathode

**CONTAINS POLYSULFONE**

To avoid stress cracking, we suggest using ND Industries' **Vibra-Tite** for thread-locking. **Vibra-Tite** evaporates fast without causing structural failure in OPTEK'S molded plastics.

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## Electrical Specifications

Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise noted)	
Storage and Operating Temperature Range	$-40^\circ\text{C}$ to $+100^\circ\text{C}$
Reverse Voltage	2.0 V
Continuous Forward Current	50 mA
Peak Forward Current	3.0 A
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron] <sup>(1)</sup>	$260^\circ\text{C}$
Power Dissipation <sup>(2)</sup>	100 mW

Electrical Characteristics ( $T_A = 25^\circ\text{C}$ unless otherwise noted)						
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
$E_{E(APT)}$	Apertured Radiant Incidence	0.40	-	-	mW/cm <sup>2</sup>	$I_F = 20\text{ mA}^{(3)}$
	OP140A, OP145A	0.30	-	0.55		
	OP140B	0.20	-	0.40		
	OP140C, OP145C	0.10	-	-		
$V_F$	Forward Voltage	-	-	1.60	V	$I_F = 20\text{ mA}$
$I_R$	Reverse Current	-	-	100	$\mu\text{A}$	$V_R = 2.0\text{ V}$
$\lambda_p$	Wavelength at Peak Emission	-	935	-	nm	$I_F = 10\text{ mA}$
B	Spectral Bandwidth between Half Power Points	-	50	-	nm	$I_F = 10\text{ mA}$
$\lambda_p / \Delta T$	Spectral Shift with Temperature	-	$\pm 0.30$	-	nm/ $^\circ\text{C}$	$I_F = \text{Constant}$
$\theta_{HP}$	Emission Angle at Half Power Points	-	40	-	Degree	$I_F = 20\text{ mA}$
$t_r$	Output Rise Time	-	1000	-	ns	$I_{F(PK)} = 100\text{ mA}$ , $PW = 10\ \mu\text{s}$ , and $D.C. = 10.0\%$
$t_f$	Output Fall Time	-	500	-	ns	

- Notes:
1. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering. A maximum of 20 grams force may be applied to the leads when soldering.
  2. Derate linearly 1.33 mW/ $^\circ\text{C}$  above  $25^\circ\text{C}$ .
  3.  $E_{E(APT)}$  is a measurement of the average apertured radiant energy incident upon a sensing area 0.180" (4.57 mm) in diameter perpendicular to and centered on the mechanical axis of the lens and 0.653" (6.60 mm) from the lens tip.  $E_{E(APT)}$  is not necessarily

# Plastic Infrared Emitting Diode

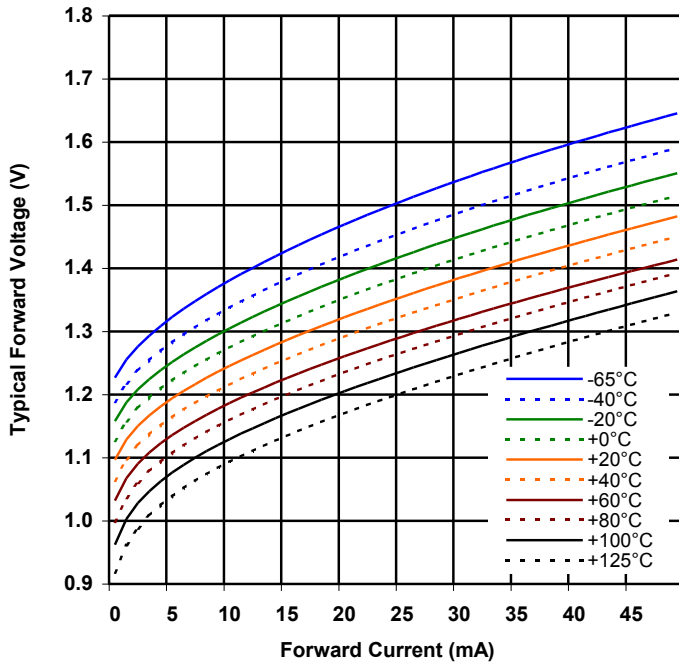
OP140, OP145 Series



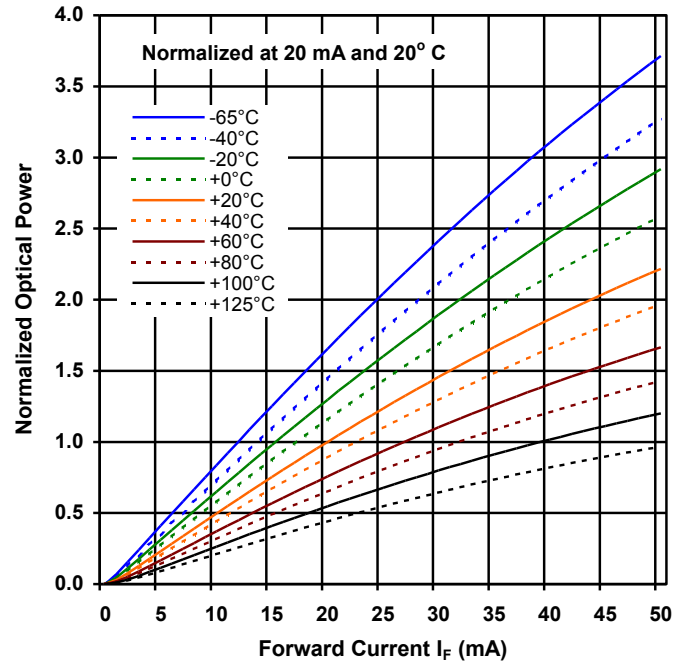
## Performance

OP140, OP145 (A, B, C, D)

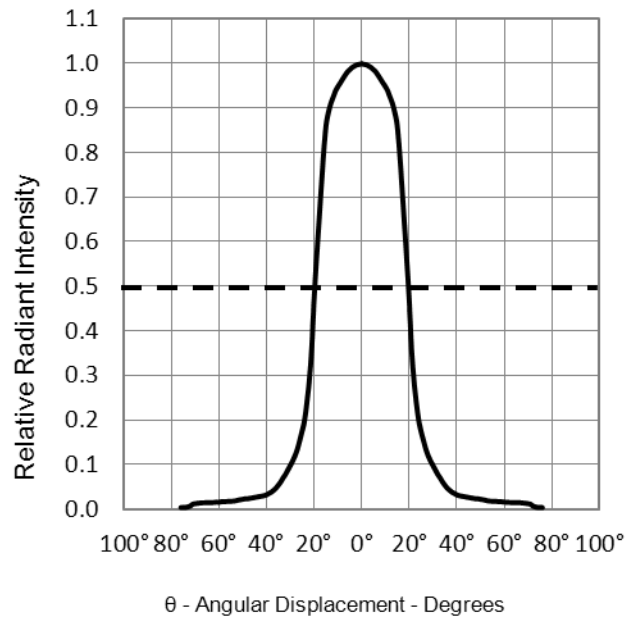
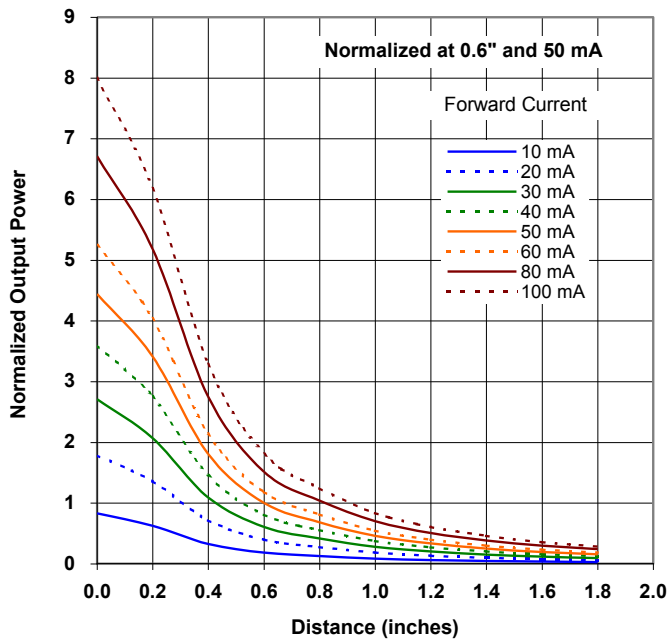
Forward Voltage vs Forward Current vs Temperature



Optical Power vs  $I_F$  vs Temp



Distance vs Output Power vs Forward Current



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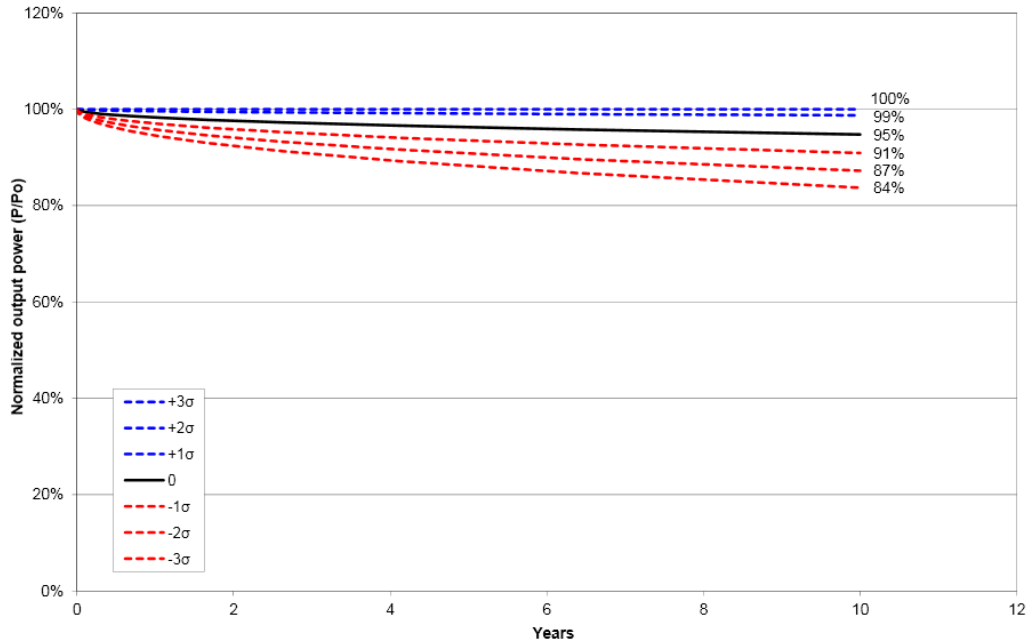
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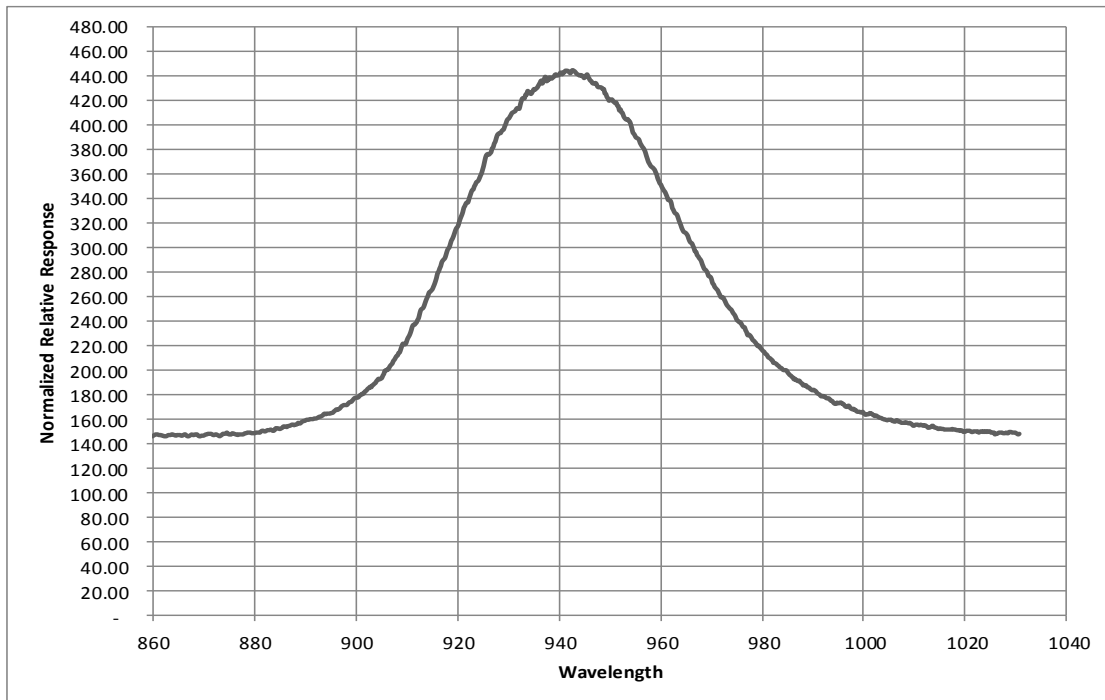


## Performance

Degradation curves of OP140 +/- 3 standard deviations  
Conditions:  $I_f = 20 \text{ mA}$



## Spectral Response



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<http://moschip.ru/get-element>

Вы можете разместить у нас заказ для любого Вашего проекта, будь то серийное производство или разработка единичного прибора.

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Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

### Офис по работе с юридическими лицами:

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